

Table Of Contents

Introduction	1
1.1 The need of photovoltaic among renewable energy sources	1
1.2 Leading role of solar cell based $\text{Cu}(\text{In}_{1-x}\text{Ga}_x)(\text{Se}_{1-y}\text{S}_y)_2$ material.	2
1.3 Purpose	3
1.4 Organization	3
1 Fundamental of CuGaSe_2	5
1.1 Relevance of chalcopyrites thin films for solar cells	5
1.2 Structural properties of CuGaSe_2	6
1.2.1 Chemical structure of CuGaSe_2 chalcopyrite compound	6
1.2.2 Phase diagram of CuGaSe_2	8
1.2.3 Electronic band structure of CuGaSe_2	10
1.3 Electrical and optical properties of CuGaSe_2 based devices	12
1.3.1 Crystal defects CuGaSe_2	12
1.3.2 Models for defect structures	12
1.3.3 Doping of CuGaSe_2	14
1.3.4 Compensation and potential fluctuations:	14
2 Review of experimental methods	16
2.1 Photoluminescence Spectroscopy (PL)	16
2.1.1 Introduction	16
2.1.2 Radiative transitions in semiconductors	17

2.1.2.1	Free excitons (Ex)	17
2.1.2.2	Bound excitons (Bx)	17
2.1.2.3	Free-to-bound transitions (FB)	18
2.1.2.4	Donor- acceptor pair recombination (DAP)	18
2.1.3	Photon-related recombinations	19
2.1.4	Experimental photoluminescence setup	19
2.2	Electron Spin Resonance	20
2.2.1	Theory of paramagnetism	20
2.2.2	Experimental apparatus	21
2.3	XRD	22
2.4	ERDA	23
2.5	SNMS	23
3	Deposition technology: Chemical closed- space vapor transport (CCSVT)	24
3.1	Chemical closed- space vapor transport (CCSVT)	24
3.1.1	CCSVT apparatus	25
3.1.2	CuGaSe ₂ film growth by CCSVT	27
3.2	Influence of the growth conditions on the CuGaSe ₂ film properties	31
3.2.1	Evolution of CuGaSe ₂ film thickness, composition, and structure.	31
3.3	Concluding remarks	35
4	Optical and structural properties of CCSVT- grown CuGaSe₂ thin films	36
4.1	Absorption coefficient and optical band gap	36
4.2	Microstructural analysis	39
4.3	Elemental depth profiles in CuGaSe ₂ thin films	42
4.4	Concluding Remarks	44

5	Photoluminescence of as-prepared and intentionally Ge-implanted CuGaSe₂	45
5.1	Ge- implantation and annealing process of CuGaSe ₂	46
5.1.1	Simulation of the Ge distribution in CuGaSe ₂ by SRIM program	46
5.1.2	Annealing of Ge implanted CuGaSe ₂	47
5.2	Depth profiling of Ge in CuGaSe ₂ by SNMS	48
5.3	Photoluminescence of CCSVT as-prepared CuGaSe ₂ thin films	49
5.3.1	Photoluminescence of CuGaSe ₂ : State of research	49
5.3.2	Photoluminescence of as-grown CCSVT CuGaSe ₂ thin films	50
5.3.2.1	Dependence of the photoluminescence spectra on the composition [Ga]/[Cu]:.....	50
5.3.2.2	Determination of the ionization energy of the donor- acceptor transition in CuGaSe ₂ films by means of excitation intensity.....	51
5.3.2.3	Defect profiles in CCSVT as-grown CCSVT films	56
5.4	Effects of Ge- implantation on the photoluminescence of CuGaSe ₂ thin films	58
5.4.1	Comparison of UV and visible photoluminescence spectra of the undoped CGSe thin films	58
5.4.2	Effect of annealing and Ge- implantation highlighted by visible PL	59
5.4.3	Effect of Ge implantation on photoluminescence highlighted by UV excitation.	61
5.4.4	Temperature dependence of peak at 1.47 eV	64
5.5	Concluding remarks:	67
6	Electron spin resonance of as-grown and Ge- implanted CuGaSe₂ thin films	69
6.1	Experimental details	69
6.2	Paramagnetic centers in as- grown and Ge- implanted CuGaSe ₂ thin films.....	69
6.2.1	Paramagnetic activity of Ge in CuGaSe ₂	70
6.2.2	ESR of as grown and Ge implanted CuGaSe ₂ films.	70

6.2.3	Assignment of ESR signals.	71
6.3	Curie paramagnetism of Ge implanted CuGaSe ₂ films	72
6.4	Determination of the spin concentration	74
6.5	Concluding remarks	75
7	Summary and outlook	77
7.1	Summary	77
7.2	Suggestions for future investigations	78
	Abbreviations	79
	List of figures.....	80
	List of tables.....	84
	Bibliography	85
	Publications.....	92
	Vitae	93
	Acknowledgments	94